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上海交通大学微机研究所·南洋电脑开发总公司

1985年世界集成电路大全

6. 存储器



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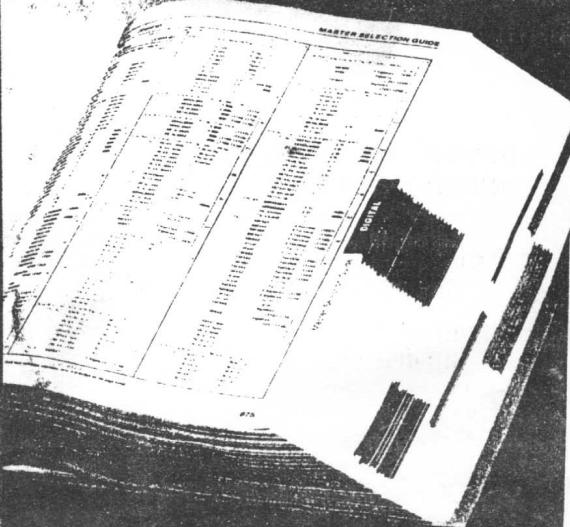
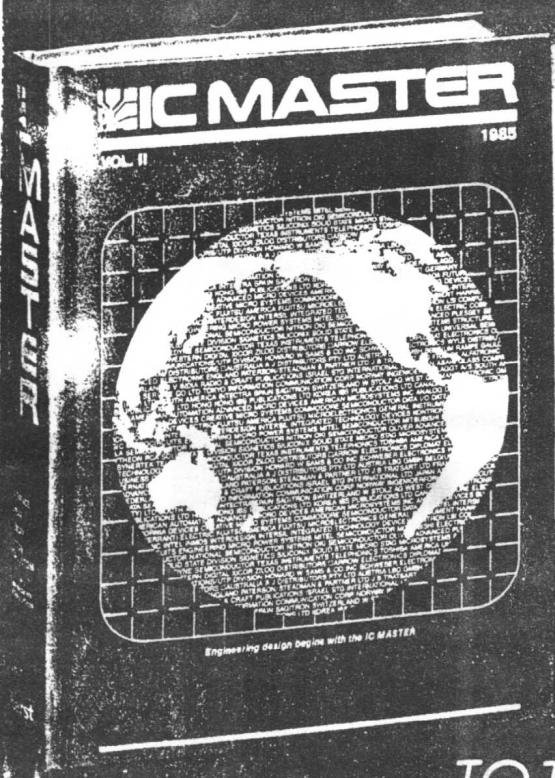
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IC MASTER

VOLUME I

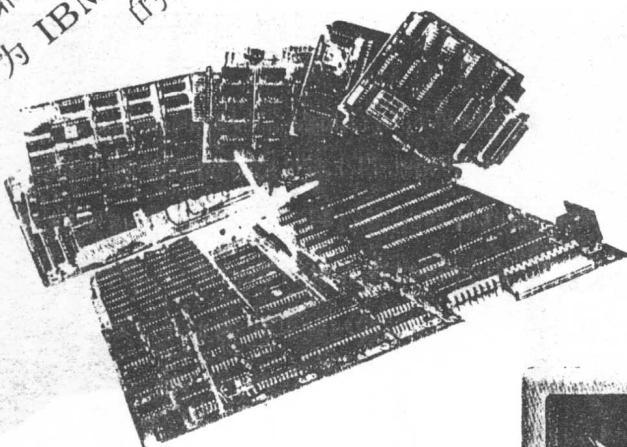
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TO THE 1985 IC MASTER

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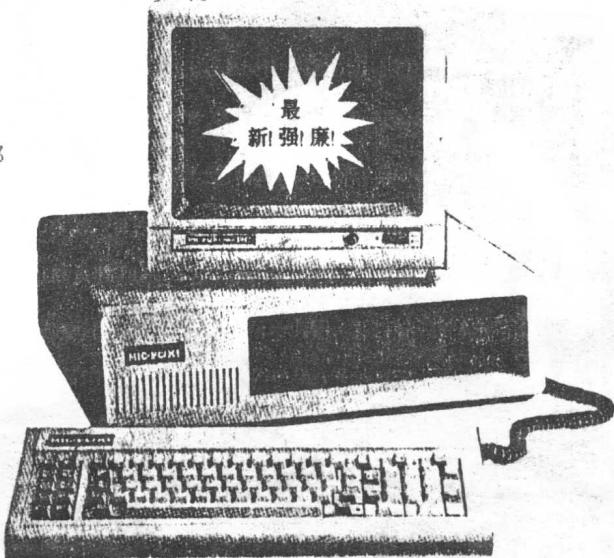
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存储器引言

《IC大全选择指南》充分提供了最初选择产品的信息，在本章节中出现的所有产品，无论是在《IC大全选择指南》中，还是在数据页中的，都包含在索引表里。索引表指出了产品在本书中的页号和引号。

存储器章节提供了最初选择信息和有关EPROM、RAM、ROM以及其它存储器的数据。在这些特殊章节中，器件由其结构（字和位/字）和存取时间来表示其特性。为了对存取时间进行比较，在器件的整个温度变化范围里（即商用器件是0°C—70°C，军用器件是-55°C—125°C）用毫微秒表示其存取时间，全部温度的毫微秒值都用“NSF”表示。不作特殊说明的话，那么在室内温度所用的毫微秒值就用“NSR”表示。在某些情况下，基准值没有建立，那么典型值就用“NS*”表示。典值一般要比基准值快快。所以快速存储器列在其它内容之前。

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The manufacturers listed above have provided detailed information on the most recent and most significant products.

EINFÜHRUNG SPEICHER

Der Master Selection Guide für Speicher enthält alle Informationen, die Sie für die Erstauswahl Ihres Produkts benötigen. Die Bauteile, die in diesem Abschnitt erscheinen, sowohl im Selection Guide als auch auf den Datenblättern, sind in allen Master Indexes enthalten. Diese Register verweisen auf die Seite und Zeile, auf der das entsprechende Bauelement vorkommt.

Der Speicherteil besteht aus einem Selection Guide und Daten über PROMs, RAMs und ROMs sowie andere Speicher-Bauteile. In diesen einzelnen Abschnitten sind die Bauteile nach Organisation (Worte und Bits/Wort) und nach Zugriffszeiten eingeteilt. Um sicherzustellen, daß die Zugriffszeiten vergleichbar sind, wurden die Werte nach Möglichkeit in Nanosekunden für den vollen zugelassenen Temperaturbereich (d.h. 0° bis 70°C für kommerzielle Bauteile und -55° bis 125°C für militärische Bauteile) angegeben. Der nsec-Wert für den vollen Temperaturbereich ist mit "nsF" bezeichnet. Wenn dieser Wert nicht genannt ist, so ist der garantierte nsec-Wert bei Raumtemperatur mit "nsR" angegeben. In einigen Fällen wurde ein garantierter Wert nicht festgelegt. Dann wird der typische Wert mit einem nachfolgenden "ns*" markiert. "Typische" Werte sind durchwegs schneller als garantierter, so daß solche Eintragungen die Speicher weiter oben in der Liste erscheinen lassen als dies sonst der Fall wäre.

INTRODUCTION AUX MEMOIRES

Le Guide Général de Sélection fournit suffisamment de renseignements pour permettre des sélections initiales de produits. Tous les appareils énumérés dans cette section, tant dans le Premier Guide de Sélection que dans les feuilles de données, sont inclus dans tous les index. Ces index vous procurent la possibilité de retrouver à quelle page et à quelle ligne tel ou tel appareil a été mentionné.

La Section "Mémoires" contient des données et des renseignements de sélection initiale sur les PROMs, les RAMs et les ROMs, ainsi que sur d'autres appareils mémoires. Dans ces sous-sections, les appareils sont distingués par définition (mots et bit/mot) et par temps d'accès. Afin d'être sûr que les temps d'accès soient comparables, chaque fois que cela a été possible, les valeurs ont été indiquées en nanosecondes pour toute la fourchette de température (exemple: 0° à 70° pour les produits industriels, et -55°C à 125°C pour les produits militaires). La valeur entière de température en nanosecondes est désignée par "nsf". Lorsque cette valeur n'est pas donnée, une valeur garantie à température ambiante, exprimée en nanosecondes, est suivie par "nsR". Dans certains cas aucune valeur garantie en nanosecondes n'a pu être établie, la valeur "typique" est alors traduite par "ns". Les valeurs "typiques" sont invariablement beaucoup plus rapides que celles dites "garanties", de sorte que ces mémoires "typiques" apparaissent plus haut sur la liste qu'elles ne le seraient sur d'autres.

INTRODUCCIÓN A MEMORIA

La Guía Maestra de Selección provee suficiente información para hacer selecciones iniciales del producto. Todas las componentes que aparecen en esta sección, ya sea en la guía de selección inicial o en las páginas de datos, están incluidas en todos los otros índices. Estas listas de índices los conduce a la página y linea de aquella página donde se encuentra cada componente.

La Sección de Memoria provee información para la selección inicial y datos de PROMs, RAMs, and ROMs así como otras piezas de memoria. En estas secciones en particular, las componentes se caracterizan por organización (palabras y bits/palabras) y por tiempo de acceso. Con objeto de asegurar que los tiempos de acceso son comparables, cuando es posible, los valores aparecen en nanosegundos sobre el intervalo completo de temperatura para las componentes (en otras palabras, 0° to 70°C para piezas de uso comercial y -55° a 125°C para piezas de uso militar). El valor del intervalo completo de temperatura está marcado "nsF". Cuando este valor no está especificado, el valor de nanosegundos está garantizado para temperatura ambiental y aparece seguido por "nsR". En algunos casos el valor no ha sido establecido; entonces el valor típico aparece seguido por "ns*". Valores "típicos" son sin falta más rápido que los garantizados de tal manera que las listas ubica estas memorias antes que normalmente los mostraría.

メモリーへの案内

マスター選択ガイドは選択に取りかかる充分な資料を揃えています。セレクションガイド、データ掲載ページにのっている製品は全てのインデックスに入っており、そのインデックスによりページ数、行数はすぐ見つけられます。

このセクションにはPROM, RAM, ROM他のメモリーのデータが入っています。製品はその構成(ワード、ビット／ワード)とアクセスタイム毎IC分類されています。アクセスタイムが同等であるかどうか確認する為可能な限り夫々の全温度範囲(一般0°C~70°C; ミリタリ-55°C~125°C)でのアクセスタイムをナノセカンドで表示しています。全温度範囲でのアクセスタイムは"ns F"と表示、規定されていないものすなわち室温での保証値は"ns R"となっています。保証値が決められていない場合は代表的値として"ns★"がついています。"Typical"値は通常保証値よりも速くつけられるのでリスト上では他に記載されているものより高い場所に記載されています。

MASTER SELECTION GUIDE

MEMORY-Character Generators

Format	Number of Lines	Output Logic Levels	Input Logic Levels	Supply Voltage, V	Device	Source	Line
Character Generators							
5x7	1	TTL	5		DM76S128	† National	
					DM76S64	† National	
					DM8678	National	
					DM86S64	National	
5	MOS	5			MM52116FDW	National	
		TTL	5		RO3-2513	GI	
					MCM6670	Motorola (4440)	
					MCM6674	Motorola (4440)	
35		TTL	5		MSL9650	OKI (4452)	
5x7	1	TTL	5		DM86S128	National	
6x10	7	MOS	5		MCH-01	Motorola	
7x9	1	TTL	5		DM76S128	† National	
					DM76S64	† National	
					DM8678	National	
					DM86S64	National	
7	MOS	5			MM52116FDX	National	
		TTL	5		MCM66700	Motorola (4440)	
					MCM66710	Motorola	
					MCM66714	Motorola	
					MCM66720	Motorola	
					MCM66730	Motorola	
					MCM66734	Motorola	
					MCM66740	Motorola	
					MCM66750	Motorola	
					MCM66751	Motorola	
					MCM66760	Motorola	
					MCM66770	Motorola	
					MCM66780	Motorola	
					MCM66790	Motorola	
7x11	1	TTL	5		CRT7004	SMC	
					CRT8002	SMC	
7x9	1	TTL	5		DM86S128	National	
10x9	10	TTL	5		SCM2670	Sigmetics (1975)	
14 Segments	14	TTL	5		MSL9664	OKI (4452)	
					MSL9665	OKI (4452)	
16 Segments	16	TTL	5		MSL9662	OKI (4452)	
					MSL9663	OKI (4452)	
16x16 Japanese	16	TTL	5		MSM28101A	OKI	
					MSM28201A	OKI	

MEMORY-Code Converters

Code Conversion From	Bits In	Bits Out	Process	Supply Voltage, V	Device	Source	Line
Code Converters							
BINARY-BCD	6	6	Bipolar	5	SN54185A	† TI (684)	
					SN74185A	TI	
Degree Sine					S086	† MMI (1165)	
					S087	† MMI (1165)	
					S086	MMI (1165)	
					S087	MMI (1165)	
EBCDIC ASCII	12	8	Bipolar	5	DM8576AAA	National	
Binary-BCD	9	7	Bipolar	5	SN54S485A	† TI	
					SN74S485A	TI	
BCD-BINARY	6	6	Bipolar	5	SN54184	† TI (684)	
					SN74184	TI	
BCD-Binary	7	9	Bipolar	5	SN54S484A	† TI	
					SN74S484A	TI	

† Military Temperature Range: -55° to 125° C.

Typical Value

Bold face indicates additional data is provided on the page noted

IC MASTER**MEMORY-FIFOs, LIFOs (Cont'd)**

Words	Bits/ Word	Data Rate MHz (max)	Supply Voltage, V	Device	Source	Line	Words	Bits/ Word	Data Rate MHz (max)	Supply Voltage, V	Device	Source	Line		
First-in First-out															
16	4	8.0 *	3-15	CD40105B CD40105BE	† RCA RCA	(1210) (1210)	64	4	15.0	5	CY7C404-15M 67401A C67401A DM77S401A SN54LS224 SN54LS224 SN74LS227 SN74LS227 SN74S225 SN74S225	Cypress MMI MMI National † National † TI (688,698,690,701) TI TI	(Cont'd) (1184) (1184,1179) National (1184,1179) (1184,1179) (1184,1179) (1184,1179)	65	
		10.0	5	54T403 74T403 N9403	† Fairchild Fairchild Signetics	(1959) (1959)	5	16.7	5	67401B C67401B	MMI MMI	(1184) (1184,1179)	70		
		12.0	5	SN54LS222 SN54LS224	† TI † TI	(688,698,690,701)	5	35.0	5	57413A 67413A	MMI MMI	(1184,1180) (1184,1180)	75		
		20.0	5	SN54LS227 SN54LS228 SN74S227 SN74S228	† TI † TI TI TI		10	5.0	5	67L402 57402	MMI MMI	(1184) (1184)	75		
	5	10.0	5	SN74S225 SN74S225	MMI TI	(1184)		7.0	5	C57402	MMI	(1184,1179)	75		
24	4	2.5	5-16	M5618	† RTC			10.0	5	CY7C402-10C CY7C404-10C	Cypress Cypress		80		
32	8	0.5	- 12.5	AM2812C AM2812L MJ2812	AMD AMD Plessey		15	5.0	5	57402A 67402 C57402A C67402A DM77S402 DM87S402	† MMI MMI † MMI MMI † National National	(1184) (1184) (1184,1179) (1184,1179) National National	80		
		10	- 12.5	AM2812AC AM2812AL	AMD AMD		20	15.0	5	CY7C402-15C CY7C404-15 CY7C404-15C	Cypress Cypress Cypress		85		
9	0.5	- 12.5	AM2813C AM2813L MJ2813	AMD AMD Plessey			20	67402A	MMI	(1184)			90		
	1.0	- 12.5	AM2813AC AM2813AL	AMD AMD			25	16.7	5	67402B C67402B	MMI MMI	(1184) (1184,1179)	90		
40	9	0.5	- 12.5	FR1502-11 33512 3351M	Western Fairchild Fairchild		30	9	15.0	5	TDC1030	TRW-LSI	(1552)		
	1.0	- 12.5	FR1502-10	Western			132/128	9	0.65	5	WD1510-00 WD1510-01	Western Western		95	
	1.5	- 12.5	3351-3	Fairchild				1.0	5	MK4501-20 MK4501-15 MKB4501-82	Mostek Mostek Mostek				
	2.0	- 12.5	33511	Fairchild				512	9	4.2	5	IDT7201-120 IDT7201-125B	IDT IDT	(1149) (1149)	100
64	4	0.7	- 12.5	AM3341C 3341 3341M	AMD Fairchild Fairchild		35	5.7	5	7	5	IDT7201-120 IDT7201-125B	IDT IDT	(1149) (1149)	100
	1.0	- 12.5	AM2841C AM2841M 3341A MJ2841	AMD AMD Fairchild Plessey			35	7.1	5	MK4501-12 MKB4501-81	Mostek	(4433)			
	1.2	5	CY3341C AM2841A	Cypress AMD			40	10	5	IDT7201-80 IDT7201-85B	IDT IDT	(1149) (1149)			
		- 12.5					40	15	5	IDT7201-50 IDT7201-55B	IDT IDT	(1149) (1149)			
7.0	5	S7401 C57401	MMI MMI	(1184) (1184,1179)			45	1024	9	7	5	IDT7202-120 IDT7202-125B	IDT IDT	(1149) (1149)	110
8.0	5	9423C 9423M	Fairchild Fairchild	(1984) (1984)			45	10	5	IDT7202-80 IDT7202-85B	IDT IDT	(1149) (1149)			
	10	5	DM77S401 DM87S401	National National			45	15	5	IDT7202-50 IDT7202-55B	IDT IDT	(1149) (1149)			
	10.0	5	CY7C401-10C CY7C401-10M CY7C402-10M CY7C403-10C CY7C403-10M CY7C404-10M 54T413 54T433 74T413 74T433 S7401A 67401 C57401A C67401	Cypress Cypress Cypress Cypress Cypress Cypress † Fairchild † Fairchild Fairchild Fairchild † MMI MMI † MMI MMI MMI	(1184) (1184) (1184,1179) (1184,1179) (1184,1179) (1184,1179)		50	64	4	5.0	5	67L401	MMI	(1184)	
							50	81	4	1.0	5	SH501B	SMC		115
								132/128	9	1.0	5	WD1510-02	Western		
								133	4	1.0	5	SH501T	SMC		
	15.0	5	CY7C401-15 CY7C402-15M CY7C403-15	Cypress Cypress Cypress											

* Military Temperature Range (-55° to 125°C)

* Typical Value

Bold face indicates additional data is provided on the page noted.

MASTER SELECTION GUIDE

MEMORY-E² PROMS

Organization	Access Time (Max)	Type	No. Output Pins	Supply Voltage, V	Device	Source	Line	Organization	Access Time (Max)	Type	No. Output Pins	Supply Voltage, V	Device	Source	Line
E² PROMs															
16x16	—	E ²	Serial 8	5	COP494 NMC9306	National National		512x8	450 nsF	E ²	TS 24	5	X2804A-45 X2804AM-45	Xicor (706.4587) † Xicor (706.4587)	(Cont'd)
			NRAM	Serial 8	5	X2444	Xicor (4584)		650 nsF	E ²	TS 24	5	HNVM3004	Hughes	60
0.4 µsF	E ²	Serial 8	5	ER59256	GI		1024x1	300 nsF	NRAM	TS 18	5	X2201A	Xicor		
400 nsF	NRAM	Serial 8	5	X2443	Xicor (4584)		1024x4	900 nsF	EA	TS 22	-30, -12	ER3400 NC7451	GI Nitron		
2000 nsF	E ² P	Serial 8	5	NCR59306	NCR (4446,4449)		1024x8	650 nsF	E ²	TS 24	5	HNVM3008 HNVM3108 HNVM3708	Hughes † Hughes Hughes	65	
16x16	160 nsF	E ²	Serial 14	5	NCR52801	NCR (4446)		2048x4	1600 nsF	EA	TS 24	-24, -14.5	ER2810 ER2810HR	GI † GI	
32x8	450 nsF	E ²	TS 18	5	HNVM3004	† Hughes		2048x8	55 nsF	E ²	TS 24	5	XL46C16-55 XL46C16-70	EXEL	70
32x16	—	EA	Serial 18	28.12	U3070	Telefunken		200 nsF	E ²	TS 24	5	S2B13200 S2B13H200	SEEQ		
	1 µsF	EA	TS 28	-28.5	ER2051	GI					28	5	XL2817A200	EXEL	75
	2 µsF	EA	TS 28	-28.5	ER2051HHR	GI							ZB17A-Z	Intel (4405)	
	4 µsF	EA	TS 28	-29.5	NC7051	Nitron							NMC981720	National	
50x14	1000 nsF	EA		-30.5	ER1451	GI							2817A-200	SEEQ	
64x4	300 nsF	NRAM	TS 18	5	NCR52210	NCR (4446,4447)							2817AH	SEEQ	
			X2210	Xicor (4583)									5517A	SEEQ	
			X2210M	Xicor (4583)									5517AH	SEEQ	
64x8	4 µsF	EA	TS 22	-29.5	ER2055	GI									
			NC7055	Nitron											
	125 nsF	NRAM	TS 24	5	R2000	Rockwell									
	300 nsF	NRAM	TS 18	5	HNVM3500	† Hughes									
64x16	0.4 µsF	E ²	Serial 8	5	ERS911	GI									
	1 µsF	E ²	Serial 8	5	NCR59308	NCR (4446,4450)									
	450 nsF	E ²	TS 16	5	COP495	National									
82x1	100 µsF	EA	TS 18	-30.5	ER0082	GI									
100x14	3400 nsF	EA	Serial 14	-35	ER1400	GI									85
100x50	3400 nsF	EA	Serial 14	30.5	ER1451	GI									
128x4	300 nsF	NRAM	TS 24	5	NCR52211	NCR (4446,4447)									
128x8	0.4 µsF	E ²	Serial 8	5	ERS911	GI									
	250 nsF	E ²	Serial 8	5	PCD8572	GI									90
	300 nsF	E ²	TS 24	5	ERS901	GI									
			ERS901HHR	† GI											
			NVRAM	TS 24	5	NCR52001	NCR (4446,4448)								
			X2001	Xicor (706.4585)											95
			X2001M	Xicor (706.4585)											
	450 nsF	NRAM	TS 24	5	NCR620001M	NCR									
256x4	300 nsF	NRAM	TS 18	5	NCR52212	NCR (4446,4447)									100
			X2212	Xicor (705.4583)											
			X2212DM	Xicor (705.4583)											
256x8	E ²	Serial 8	5	X2402	Xicor (4588)										
	250 nsF	E ²		ER902	GI										
	300 nsF	NRAM	TS 24	5	NCR52002	NCR (4446,4448)									105
			X2002	Xicor (706.4585)											
			X2002M	Xicor (706.4585)											
512x8	200 nsF	NRAM	TS 28	5	2004_2	Intel									
	250 nsF	E ²	TS 24	5	ER590	GI									
			TS 24	5	X2804A-25	Xicor (706.4587)									
			NVRAM	TS 28	5	2004	Intel								
	300 nsF	E ²	TS 24	5	X2804A	Xicor (706.4587)									
			X2804AM	Xicor (706.4587)											
			NVRAM	TS 24	5	NCR52004	NCR (4446,4448)								
			2004_3	Intel											
			NCR52004_28	NCR (4446,4448)											
			X2004	Xicor (706.4585)											
			X2004M	Xicor (706.4585)											
	350 nsF	E ²	TS 24	5	X2804A-35	Xicor (706.4587)									
			X2804AM-35	Xicor (706.4587)											
			(Continued)												

[†] Military Temperature Range [±] In 125 °C ^{ns} Nanoseconds ^{nsF} Nanoseconds over Full Temperature Range ^{nSR} Nanoseconds at Room Temperature ^{OF} Open Emitter

Master Selection Guide

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MEMORY-E² PROMs (Cont'd)

[†] Military Temperature Range (-55° to 125° C)

• Typical Value

Bold face indicates additional data is provided on the page noted.

MASTER SELECTION GUIDE

MEMORY-PROMs

Organization	Access Time (Max)	Type	Supply				Line	Organization	Access Time (Max)	Type	Output	No. Pins	Supply Voltage V	Device	Source	
			No.	Pins	Voltage	Device										
PROMs																
16x4	25 nsF	TTL	TS	16	5	DM85547A	National		256x4	35 nsF	TTL	OC	16	5	HM76108-5	Harris (4356) (Cont'd)
	30 nsF	TTL	TS	16	5	DM7507A	† National					TS	16	5	HM7611B-5	Harris
35 nsF	TTL	OC	16	5	DM85506	National			40 nsF	TTL	OC	16	5	AM27S20AM	† AMD	
			TS	16	5	DM85507	National					TS	16	5	AM27S21AM	† AMD
50 nsF	TTL	OC	16	5	DM75506	† National									53S141A	† MMI (4414)
			TS	16	5	DM75507	† National		45 nsF	TTL	OC	16	5	AM27S20C	AMD	
32x8	15 nsF	TTL	OC	16	5	DM87S188	National								HM7610A-5	Harris (4356)
			TS	16	5	53S081A	† MMI (4414)					TS	16	5	63S140	† MMI (4414)
20 nsF	TTL	OC	16	5	DM77S188	† National								AM27S21C	AMD	
			TS	16	5	DM77S288	† National							HM7611A-5	Harris	
20 nsR	ECL	OE	16	-5.2	SN10139	TI									63S141	† MMI (4414)
25 nsF	ECL	OE	16	5.2	MCM10139	Motorola (4443)									HM7610B-2	† Harris (4356)
	TTL	OC	16	5	AM27S19AC	AMD								DM74S287	National	
			TS	16	5	53S0801A	† MMI (4414)							HM82S126	Signetics (4476)	
					53S0801	MMI (4414)								TS	16	5
					MCM27S19	Motorola								HM7611B-2	† Harris	
					AM27S19AC	AMD								DM74S287	National	
					53S080	† MMI (4414)								HM82S129	Signetics (4476)	
					AM27S19AC	AMD								53S140	† MMI (4414)	
					53S0801A	† MMI (4414)								63S001	MMI	
					53S0801	MMI (4414)								TS	16	5
					MCM27S19	Motorola								63S141	† MMI (4414)	
					AM27S19AC	AMD								TS	16	5
					53S080	† MMI (4414)								HM7611B-2	† Harris	
					AM27S19AC	AMD								DM74S287	National	
					53S0801A	† MMI (4414)								HM82S126	Signetics (4476)	
					AM27S19AC	AMD								53S0801	† MMI (4414)	
					53S0801A	† MMI (4414)								63S001	MMI	
					AM27S19AC	AMD								TS	16	5
					53S0801A	† MMI (4414)								63S140	† MMI (4414)	
					AM27S19AC	AMD								TS	16	5
					53S0801A	† MMI (4414)								63S141	† MMI (4414)	
					AM27S19AC	AMD								TS	16	5
					53S0801A	† MMI (4414)								HM7611B-2	† Harris	
					AM27S19AC	AMD								DM74S287	National	
					53S0801A	† MMI (4414)								HM82S126	Signetics (4476)	
					AM27S19AC	AMD								53S0801	† MMI (4414)	
					53S0801A	† MMI (4414)								63S001	MMI	
					AM27S19AC	AMD								TS	16	5
					53S0801A	† MMI (4414)								63S140	† MMI (4414)	
					AM27S19AC	AMD								TS	16	5
					53S0801A	† MMI (4414)								63S141	† MMI (4414)	
					AM27S19AC	AMD								TS	16	5
					53S0801A	† MMI (4414)								HM7611B-2	† Harris	
					AM27S19AC	AMD								DM74S287	National	
					53S0801A	† MMI (4414)								HM82S126	Signetics (4476)	
					AM27S19AC	AMD								53S0801	† MMI (4414)	
					53S0801A	† MMI (4414)								63S001	MMI	
					AM27S19AC	AMD								TS	16	5
					53S0801A	† MMI (4414)								63S140	† MMI (4414)	
					AM27S19AC	AMD								TS	16	5
					53S0801A	† MMI (4414)								63S141	† MMI (4414)	
					AM27S19AC	AMD								TS	16	5
					53S0801A	† MMI (4414)								HM7611B-2	† Harris	
					AM27S19AC	AMD								DM74S287	National	
					53S0801A	† MMI (4414)								HM82S126	Signetics (4476)	
					AM27S19AC	AMD								53S0801	† MMI (4414)	
					53S0801A	† MMI (4414)								63S001	MMI	
					AM27S19AC	AMD								TS	16	5
					53S0801A	† MMI (4414)								63S140	† MMI (4414)	
					AM27S19AC	AMD								TS	16	5
					53S0801A	† MMI (4414)								63S141	† MMI (4414)	
					AM27S19AC	AMD								TS	16	5
					53S0801A	† MMI (4414)								HM7611B-2	† Harris	
					AM27S19AC	AMD								DM74S287	National	
					53S0801A	† MMI (4414)								HM82S126	Signetics (4476)	
					AM27S19AC	AMD								53S0801	† MMI (4414)	
					53S0801A	† MMI (4414)								63S001	MMI	
					AM27S19AC	AMD								TS	16	5
					53S0801A	† MMI (4414)								63S140	† MMI (4414)	
					AM27S19AC	AMD								TS	16	5
					53S0801A	† MMI (4414)								63S141	† MMI (4414)	
					AM27S19AC	AMD								TS	16	5
					53S0801A	† MMI (4414)								HM7611B-2	† Harris	
					AM27S19AC	AMD								DM74S287	National	
					53S0801A	† MMI (4414)								HM82S126	Signetics (4476)	
					AM27S19AC	AMD								53S0801	† MMI (4414)	
					53S0801A	† MMI (4414)								63S001	MMI	
					AM27S19AC	AMD								TS	16	5
					53S0801A	† MMI (4414)								63S140	† MMI (4414)	
					AM27S19AC	AMD								TS	16	5
					53S0801A	† MMI (4414)								63S141	† MMI (4414)	
					AM27S19AC	AMD								TS	16	5
					53S0801A	† MMI (4414)								HM7611B-2	† Harris	
					AM27S19AC	AMD								DM74S287	National	
					53S0801A	† MMI (4414)								HM82S126	Signetics (4476)	
					AM27S19AC	AMD								53S0801	† MMI (4414)	
					53S0801A	† MMI (4414)								63S001	MMI	
					AM27S19AC	AMD								TS	16	5
					53S0801A	† MMI (4414)								63S140	† MMI (4414)	
					AM27S19AC	AMD								TS	16	5
					53S0801A	† MMI (4414)								63S141	† MMI (4414)	
					AM27S19AC	AMD								TS	16	5
					53S0801A	† MMI (4414)								HM7611B-2	† Harris	
					AM27S19AC	AMD								DM74S287	National	
					53S0801A	† MMI (4414)								HM82S126	Signetics (4476)	
					AM27S19AC	AMD								53S0801	† MMI (4414)	
					53S0801A	† MMI (4414)								63S001	MMI	
					AM27S19AC	AMD								TS	16	5
					53S0801A	† MMI (4414)								63S140	† MMI (4414)	
					AM27S19AC	AMD								TS	16	5
					53S0801A	† MMI (4414)								63S141	† MMI (4414)	
					AM27S19AC	AMD								TS	16	5
					53S0801A	† MMI (4414)								HM7611B-2	† Harris	
					AM27S19AC	AMD								DM74S287	National	
					53S0801A	† MMI (4414)								HM82S126	Signetics (4476)	
					AM27S19AC	AMD								53S0801	† MMI (4414)	
					53S0801A	† MMI (4414)								63S001	MMI	
					AM27S19AC	AMD								TS	16	5
					53S0801A	† MMI (4414)								63S140	† MMI (4414)	
					AM27S19AC	AMD								TS	16	5
					53S0801A	† MMI (4414)								63S141	† MMI (4414)	
					AM27S19AC	AMD								TS	16	5
					53S0801A	† MMI (4414)								HM7611B-2	† Harris	
					AM27S19AC	AMD								DM74S287	National	
					53S0801A	† MMI (4414)								HM82S126	Signetics (4476)	
					AM27S19AC	AMD								53S0801	† MMI (4414)	
					53S0801A	† MMI (4414)								63S001	MMI	
					AM27S19AC	AMD								TS	16	5
					53S0801A	† MMI (4414)								63S140	† MMI (441	

[†] Military Temperature Range 55 to 125 °C

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nsF Nanoscrolls over Full Temperature Range

NMR Measurements at Room Temperature

OC Open Collector

Three State ---

Properties of Open Emitter

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IC MASTER**MEMORY-PROMs (Cont'd)**

Organization	Access Time (Max)	Type	Output	No. Pins	Supply Voltage.	Device	Source	Line
PROMs								
(Cont'd)								
256x8	80 nsF	TTL	OC	20	5	(Cont'd)		
						5308-1	† MMI	(4414)
			TS	20	5	5308-1	† MMI	(4414)
						TBP28LA2M	† TI	
						TBP28L22M	† TI	
	550 nsF	Erasable	TS	24	-9.5	AM1702A-1	AMD	
						AM1702AL-1	AMD	
	650 nsF	Erasable	TS	24	-9.5	AM1702A-2	AMD	
						AM1702AL-2	AMD	
512x4	30 nsF	TTL	OC	16	5	AM27S12AC	AMD	
						AM27S13AC	AMD	
			TS	16	5	532Z41A	MMI	(4414)
						HM7620B-5	Harris	(4358)
						AM27S13AM	† AMD	
						HM7621B-5	Harris	
						532Z41A	MMI	(4414)
	45 nsF	TTL	OC	16	5	632Z40	MMI	(4414)
			TS	16	5	632Z41	MMI	(4414)
	50 nsF	TTL	OC	16	5	AM27S13C	AMD	
						HM7620A-5	Harris	(4358)
						N828130	Signetics	(4477)
						AM27S13D	AMD	
						HM7621A-5	Harris	
						MCM7621A	Motorola	(4443)
						N828131	Signetics	(4477)
						24	5	
	55 nsF	TTL	OC	16	5	AMC7641A	Motorola	(4443)
						HM7620B-2	Harris	(4358)
						532Z40	† MMI	(4414)
						DM745570	National	
						DM745570A	National	
						TS	16	
						HM7621B-2	Harris	
						532Z41	† MMI	(4414)
						DM745571	National	
						DM745571A	National	
						DM745571B	National	
	60 nsF	TTL	OC	16	5	AM27S12M	† AMD	
						6305-1	MMI	
						TS	16	
						AM27S13M	† AMD	
						6306-1	MMI	
	65 nsF	TTL	OC	16	5	DM54S570	National	
						DM54S571	National	
						TS	16	
						DM54S571	National	
						DM54S571A	National	
						DM54S571B	National	
	70 nsF	TTL	OC	16	5	HM7620-5	Harris	(4358)
						HM7620A-2	Harris	(4358)
						N828130	Signetics	(4477)
						TS	16	
						HM7621-5	Harris	
						HM7621A-2	Harris	
						MCM7621	Motorola	(4443)
						N828131	Signetics	(4477)
	75 nsF	TTL	OC	16	5	5305-1	† MMI	
						5306-1	† MMI	
	85 nsF	TTL	OC	16	5	HM7620-2	Harris	(4358)
						HM7621-2	Harris	
512x8	15 nsF	REG	TS	24	5	63RA401A	MMI	(4414, 4418)
						TBP28H45	TI	
	20 nsF	Reg	TS	24	5	AM27S25AC	AMD	
						53RA401A	† MMI	(4414, 4418)
	20 nsF	Reg	TS	24	5	63RA401B	MMI	(4414, 4418)
						AM27S25AM	AMD	
	25 nsF	Reg	TS	24	5	534A481	† MMI	
						AM27S25AM	AMD	
						REG	TS	24
						534A481	† MMI	

(Continued)

† Military Temperature Range (-55° to 125°C)

* Typical Value

Bold face indicates additional data is provided on the page noted

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MEMORY-PROMS (Cont'd)

Organization	Access Time (Max)	Type	Supply Voltage, V	Device	Source	Line	Organization	Access Time (Max)	Type	Supply Voltage, V	Device	Source	Line	
PROMs				(Cont'd)			512x8						(Cont'd)	
512x8	60 nsF	TTL	OC	24 5	HM7640A-2 † Harris (4357)		300 nsF	CMOS Erasable	TS	24 10	IM6654A Intersil	(4412)		
					DM54575A † National		450 nsF	CMOS Erasable	TS	24 5	IM6654-I Intersil	(4412)		
					HM7649-5 Harris		550 nsF	CMOS Erasable	TS	24 5	IM6654 Intersil	(4412)		
					DM545472 † National		600 nsF	CMOS Erasable	TS	24 5	IM6654M Intersil	(4412)		
					DM545472A † National		1024x4	20 nsF	DOC	TS	24 5	630A441 MM	(4427)	65
					DM545472B † National			630A442 MM				630A441 MM	(4414)	
					DM545474A † National		25 nsF	DOC	TS	24 5	53D441 MM	(4427)		
					DM545474B † National			53D442 MM				53D442 MM	(4414)	
					DM745472 National		Reg	TS	24 5	AM27S65AC AMD	(4301)			70
					TBP28542 TI		30 nsF	Reg	TS	24 5	AM27S65AM AMD	(4301)		
					AM27S65C AMD			AM27S65M AMD				AM27S65M AMD	(4301)	
					24 5 AM27S15C AMD		35 nsF	Reg	TS	24 5	AM27S65M AMD	(4301)		
					HM7641A-2 † Harris			TTL	OC	18 5	AM27S2AC AMD			
					HM7649A-2 † Harris						AM27S3AC AMD			
					N825115 Signetics						M8712H Fujitsu			
					N825141 Signetics						TS 18 5 AM27S3AC AMD		75	
					TBP28546 TI						M8712H Fujitsu			
					5341-80 MM (4414)						63S441A MM	(4414)		
					DM545473 † National						DM745573B National			
					TBP28542 TI						N825137B Signetics	(4480)	80	
					24 5 DM545475 † National						TS 18 5 TBP245A4 TI			
					DM745475 National						TBP245A4M TI			
					TBP28546 TI						TS 18 5 TBP245A4 TI			
					TS 20 5 AM27S29M † AMD						TS 18 5 TBP245A4M TI			
					AM27S31M † AMD						TS 18 5 TBP245A4M TI			
					DM745474 National						TS 18 5 TBP245A4M TI			
					24 5 5348-1 MM (4414)						TS 18 5 TBP245A4M TI			
					AM27S30M † AMD						TS 18 5 TBP245A4M TI			
					HM7640-5 Harris (4357)						TS 18 5 TBP245A4M TI			
					6340-1 MM (4414)						TS 18 5 TBP245A4M TI			
					TS 20 5 5349-2 MM (4414)						TS 18 5 TBP245A4M TI			
					6349-1 MM (4414)						TS 18 5 TBP245A4M TI			
					29623 Raytheon						TS 18 5 TBP245A4M TI			
					TBP28542M TI						TS 18 5 TBP245A4M TI			
					TBP28542M TI						TS 18 5 TBP245A4M TI			
					24 5 HM7641-5 Harris						TS 18 5 TBP245A4M TI			
					5341-2 † MM (4414)						TS 18 5 TBP245A4M TI			
					6341-1 MM (4414)						TS 18 5 TBP245A4M TI			
					MCM7641 Motorola (4443)						TS 18 5 TBP245A4M TI			
					DM545474 † National						TS 18 5 TBP245A4M TI			
					TBP28546M TI						TS 18 5 TBP245A4M TI			
					80 nsF TTL OC 20 5 5348-1 MM (4414)						TS 18 5 TBP245A4M TI			
					5340-1 † MM (4414)						TS 18 5 TBP245A4M TI			
					TS 20 5 HM7649-2 Harris						TS 18 5 TBP245A4M TI			
					5349-1 † MM (4414)						TS 18 5 TBP245A4M TI			
					24 5 5341-1 † MM (4414)						TS 18 5 TBP245A4M TI			
					TS 20 5 HM7640-2 † Harris (4357)						TS 18 5 TBP245A4M TI			
					24 5 TBP28542M TI						TS 18 5 TBP245A4M TI			
					TS 20 5 TBP28542M TI						TS 18 5 TBP245A4M TI			
					24 5 HM7641-2 Harris						TS 18 5 TBP245A4M TI			
					AM27S15M † AMD						TS 18 5 TBP245A4M TI			
					S825115 Signetics						TS 18 5 TBP245A4M TI			
					S825141 Signetics						TS 18 5 TBP245A4M TI			
					TBP28146 TI						TS 18 5 TBP245A4M TI			
					250 nsF CMOS TTL TS 24 5 HM6641-2 † Harris (4366)						TS 18 5 TBP245A4M TI			
					HM6641-8 † Harris (4366)						TS 18 5 TBP245A4M TI			
					HM6641-9 † Harris (4366)						TS 18 5 TBP245A4M TI			
					CMOS RII TS 24 5 HS6641RH † Harris (633) (Continued)						TS 18 5 TBP245A4M TI			

¹ Military Temperature Range: -55 to 125°C
² ns = Nanoseconds, typical
³ nsF = Nanoseconds at Full Temperature Range

1S = Three State

⁴ ns = Nanoseconds at Room Temperature
⁵ Open Emitter

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MEMORY-PROMs (Cont'd)

[†] Military Temperature Range (-55° to 125°C).

Typical Value

Gold line indicates additional data is provided on the page cited.